

FAIRCHILD SEMICONDUCTOR FDME1023PZT Dual MOSFET, Dual P Channel, - 2.6A, -20V, 0.095Ω, -4.5V, -600mV

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	MicroFET 1.6 x 1.6 Thin
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FDME1023PZT or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.



## General Description

This device is designed specifically as a single package solution for the battery charges switch in cellular handset and other ultra-portable applications. It features two independent P-Channel MOSFETs with low on-state resistance for minimum conduction losses. When connected in the typical common source configuration, bi-directional current flow is possible. The MicroFET 1.6x1.6 Thin package offers exceptional thermal performance for it's physical size and is well suited to switching and linear mode applications.

## Features

Max = -4.5 V,>

Max = -2.5 V,>

Max = -1.8 V,>

Max = -1.5 V,>

Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin

## Application

ONSEMI

## Related Products



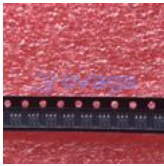
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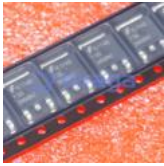
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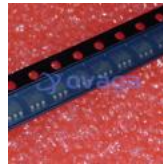
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